

EAST - (10790760 yttrium doped BST hi dielectric film for capacitor.wsp.1)

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☒ L33: (10) 32 same 2  
☒ L35: (788218) 8.ab.  
☒ L36: (7) 34 and 35  
☒ L37: (2) 34 not 36  
☒ L34: (9) 32 and 2  
☒ L38: (59079) (lower bottom) adj electrode  
☒ L39: (48221) (upper top) adj electrode  
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☒ L41: (31883) second adj 8  
☒ L42: (117) 39 near 3 40  
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☒ L55: (15) 52 and 8  
☒ L56: (690) (shar\$4) adj electrode  
☒ L57: (24) 8 near 4 58

8 near 4 58

May 2005

U	Inventor	Document	Issued	Title	Current	Current	Retrieval	S	C	P	Image	Doc
1	Deuso, Dani	US 200301	2003	2	Ceramic chip capacitor of conventional	361/32						US 200301
2	Deuso, Dani	US 200301	2003	2	Ceramic chip capacitor of conventional	361/32						US 200301
3	Amatsuchi, US	200200	2002	15	Plasma display panel	313/58						US 200200
4	Harui, Seiji	US 200100	2001	71	Dynamic random access memory (DRAM)	365/14	257/127.0					US 200100
5	Kar-Roy, Arj	US 677777	6	2004	10	High density composite MIM capacitor	257/59	257/310:				US 677777
6	Deuso, Dani	US 675321	6	2004	27	CERAMIC CHIP CAPACITOR OF CONVENTIO	438/24	361/23:				US 675321
7	Deuso, Dani	US 675108	2	2004	2	CERAMIC CHIP CAPACITOR OF CONVENTIO	361/32	361/306.1:				US 675108
8	Amatsuchi, US	683836	2003	14	Plasma display panel	313/58						US 683836
9	Hg, Chit He	US 662404	2003	12	Self-Integrated vertical MIM capacitor	438/42	257/121.01					US 662404
10	Deuso, Dani	US 654235	2003	27	CERAMIC CHIP CAPACITOR OF CONVENTIO	361/32	361/306.1:					US 654235

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